

#18/Amoldt E  
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C. Moore

Attorney's Docket No.: 07977-088002/US3155D1

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : H. Zhang                      Art Unit : 2814  
Serial No.: 09/362,808                      Examiner : S. Rao  
Filed : July 28, 1999                      Confirmation No. 7320  
Title : METHOD OF FABRICATING SEMICONDUCTOR DEVICE

BOX RCE

Commissioner for Patents  
Washington, D.C. 20231

AMENDMENT

Sir:

Please amend the above-referenced application as follows.

In the Claims:

Please amend the claims as follows.

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OCT 31 2002

TECHNOLOGY CENTER 2800

1. (Amended) A semiconductor device comprising:

E<sup>1</sup>  
a semiconductor having at least channel, source and  
drain regions;  
an insulating film formed on said semiconductor;  
a gate electrode over the insulating film;  
a first interlayer insulating film over said insulating  
film and the gate electrode;

CERTIFICATE OF TRANSMISSION BY FACSIMILE

I hereby certify that this correspondence is being transmitted by  
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